NSN 5962-01-205-3362

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-205-3362

Operating Tempurature Range:
-55.0/+125.0 degrees celsius
End Application:
Bmews iii
Inclosure Configuration:
Dual-in-line
Product Name:
Programmed 512 x 4 prom
Voltage Rating And Type Per Characteristic:
5.0 volts power source
Time Rating Per Chacteristic:
85.00 nanoseconds input to output access
Memory Device Type:
Rom
Terminal Type And Quantity:
16 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0